

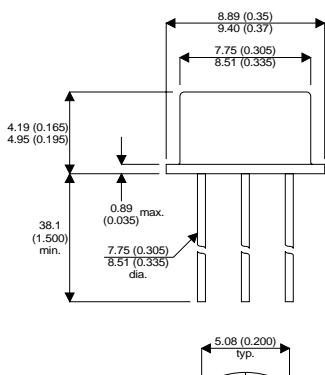


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BCY39A

MECHANICAL DATA

Dimensions in mm



TO-5

Pin1 - Emitter

Pin2 - Base

Pin3 - Collector

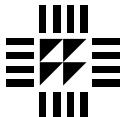
SMALL SIGNAL PNP TRANSISTORS IN TO-5

APPLICATIONS

Small signal PNP transistors for relay switching resistor logic circuits and general purpose applications.

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^\circ\text{C}$ unless otherwise stated)

V_{CBO}	Collector – Base Voltage	-64V
V_{CEX}	Collector – Emitter Voltage	-64V
V_{CE}	Collector – Emitter Voltage ($I_C = 500\text{mA}$)	-60V
V_{EBO}	Emitter – Base Voltage	-12V
$I_{C(PK)}$	Peak Collector Current	500mA
$I_{C(AV)}$	Continuous Collector Current	250mA
I_{EM}	Emitter Peak Current	500mA
$I_{E(AV)}$	Continuous Emitter Current	250mA
I_{BM}	Base Peak Current	125mA
$I_{B(AV)}$	Continuous Base Current	125mA
P_{TOT}	Total Power Dissipation	410mW
T_J	Junction Temperature	150°C
T_{stg}	Storage Temperature	150°C



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THERMAL CHARACTERISTICS

CHARACTERISTIC		
$\theta_{j\text{-amb}}$	Junction To Ambient	0.3°C/mW
$\theta_{j\text{-case}}$	Junction To Case	0.12°C/mW

ELECTRICAL CHARACTERISTICS ($T_{\text{case}} = 25^\circ\text{C}$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO} Collector Cut-Off Current	$V_{\text{CB}} = -6\text{V}$ $I_E = 0$		1	100	nA
	$V_{\text{CB}} = -6\text{V}$ $I_E = 0$ $T_{\text{amb}} = 100^\circ\text{C}$		0.1	2.5	μA
I_{EBO} Emitter Cut-Off Current	$V_{\text{EB}} = -6\text{V}$ $I_C = 0$		1	100	nA
	$V_{\text{EB}} = -6\text{V}$ $I_C = 0$ $T_{\text{amb}} = 100^\circ\text{C}$		0.1	2.5	μA
h_{FE} DC Current Gain	$I_C = 30\text{mA}$ $V_{\text{CE}} = -1\text{V}$	12	30		—
	$I_C = 150\text{mA}$ $V_{\text{CE}} = -1\text{V}$	10		50	
	$I_{\text{CM}} = 300\text{mA}$ $V_{\text{CE}} = -6\text{V}$			15	
$V_{\text{CE(SAT)}}$ Collector-Emitter Saturation Voltage	$I_C = 150\text{mA}$ $I_B = 15\text{mA}$		-0.46	-1.1	V
V_{BE} Base-Emitter Voltage	$I_C = 150\text{mA}$ $I_B = -1\text{V}$		-1.5	-1.9	
I_B Base Current	$I_E = 150\text{mA}$ $V_{\text{CB}} = 0$	3		14	mA
NF Noise Figure	$I_C = 500\mu\text{A}$ $V_{\text{CE}} = -2\text{V}$ $f = 1\text{kc/s}$ $R_S = 500\Omega$		8		dB
h_{fe} Small Signal Current Gain	$I_C = 10\text{mA}$ $V_{\text{CE}} = -6\text{V}$ $f = 1\text{kc/s}$	15	35	100	—
f_T Transistion Frequency	$I_C = 1\text{mA}$ $V_{\text{CE}} = -6\text{V}$	0.45	1.5		MHz

* Pulse test : Pulse Width < 300μs ,Duty Cycle < 2%